

View Online at <https://aerobasegroup.com/nsn/5962-01-460-9459>

Maximum Power Dissipation Rating:

5000.0 milliwatts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

End Application:

Electrical e/i fscm 81349

Features Provided:

Monolithic and 3-state output

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Design Function And Quantity:

1 buffer, tri-state

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, advanced bipolar cmos, octal buffer/driver / noninverting three-state outputs, ttl comp inputs, monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Test Data Document:

96906-mil-std-833 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0